



### **40V N-Channel Enhancement Mode MOSFET**

Voltage

40 V

Current

50 A

#### **Features**

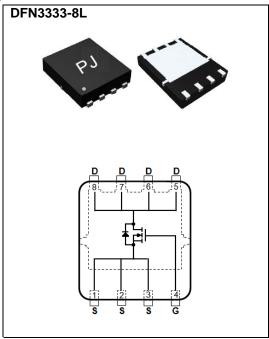
- $R_{DS(ON)}$ ,  $V_{GS}@10V$ ,  $I_D@20A<7.5m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@4.5V$ ,  $I_{D}@10A<10.5m\Omega$
- Advanced Trench Process Technology
- High density cell design for ultralow on-resistance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

• Case: DFN3333-8L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.001 ounces, 0.03 grams



### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	40	- V	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20		
Continuous Drain Current	T <sub>C</sub> =25°C	I <sub>D</sub>	50	А	
	Tc=100°C		32		
Pulsed Drain Current(Note 1)	T <sub>C</sub> =25°C	I <sub>DM</sub>	200		
Power Dissipation	Tc=25°C	Po	53.6	14/	
	T <sub>C</sub> =100°C		26.8	W	
Continuous Drain Current	T <sub>A</sub> =25°C	l <sub>D</sub>	12.7	А	
	T <sub>A</sub> =70°C		10		
Power Dissipation	T <sub>A</sub> =25°C	-	2.4	W	
Power Dissipation	T <sub>A</sub> =70°C	Pb	1.6		
Operating Junction and Storage Temperature Range		$T_{J}$ , $T_{STG}$	-55~175	°C	
Typical Thermal Resistance <sup>(Note 4,5)</sup>	Junction to Case	R <sub>0</sub> JC	2.8	°C/W	
	Junction to Ambient	$R_{\theta JA}$	62.5		

• Limited only By Maximum Junction Temperature





### **Electrical Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	40	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	1	1.61	2.5	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	6.3	7.5	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =10A	-	8	10.5	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =40V, V <sub>GS</sub> =0V	-	-	1	uA
Gate-Source Leakage Current	Igss	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic <sup>(Note 6)</sup>						
Total Gate Charge	$Q_g$	V <sub>DS</sub> =20V, I <sub>D</sub> =10A, V <sub>GS</sub> =4.5V <sup>(Note 1,2)</sup>	-	17	-	nC
Gate-Source Charge	$Q_gs$		-	4.9	-	
Gate-Drain Charge	$Q_gd$		-	6.4	-	
Input Capacitance	Ciss	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V,	-	1759	-	pF
Output Capacitance	Coss		-	176	-	
Reverse Transfer Capacitance	Crss	f=1MHZ	-	126	-	
Turn-On Delay Time	td <sub>(on)</sub>	$V_{DD}$ =15V, $I_{D}$ =1A, $V_{GS}$ =10V, $R_{G}$ =6 $\Omega$	-	11	-	
Turn-On Rise Time	tr		-	21	-	ns
Turn-Off Delay Time	td <sub>(off)</sub>		-	40	-	
Turn-Off Fall Time	t <sub>f</sub>	(1000 1,2)	-	25	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	_		-	-	50	А
Diode Forward Current	Is					
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =1A, V <sub>GS</sub> =0V	-	0.7	1	V

#### NOTES:

- 1. Pulse width<a>300us</a>, Duty cycle<a>2%</a>.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature T<sub>J(MAX)</sub>=150°C. Ratings are based on low frequency and duty cycles to keep initial T<sub>J</sub> =25°C.
- 4. The maximum current rating is package limited.
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.





#### **TYPICAL CHARACTERISTIC CURVES**

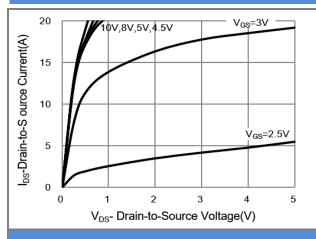


Fig.1 On-Region Characteristics

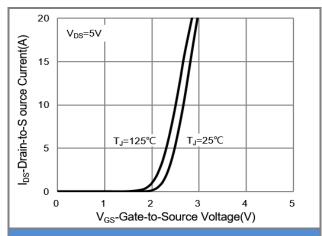


Fig.2 Transfer Characteristics

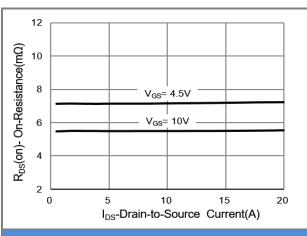


Fig.3 On-Resistance vs. Drain Current

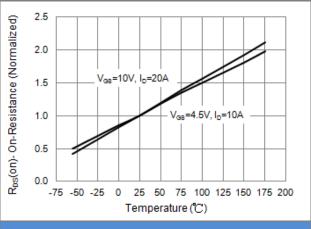


Fig.4 On-Resistance vs. Junction temperature

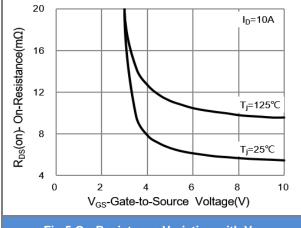


Fig.5 On-Resistance Variation with V<sub>GS</sub>

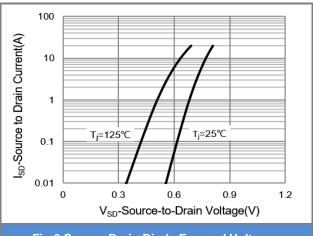


Fig.6 Source-Drain Diode Forward Voltage





#### TYPICAL CHARACTERISTIC CURVES

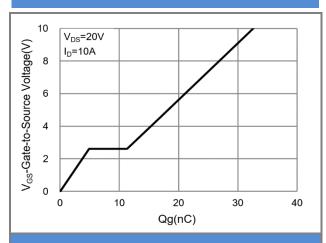


Fig.7 Gate-Charge Characteristics

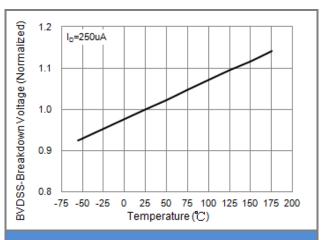


Fig.8 Breakdown Voltage Variation vs. Temperature

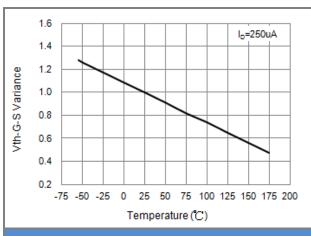


Fig.9 Threshold Voltage Variation with Temperature

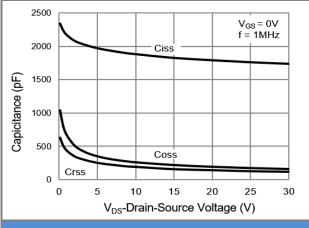
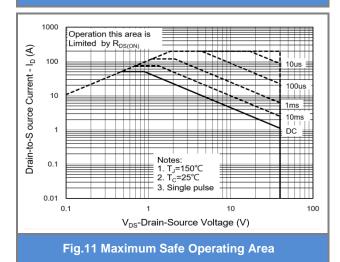


Fig.10 Capacitance vs. Drain-Source Voltage



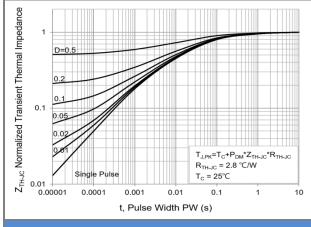


Fig.12 Normalized Transient Thermal Impedance

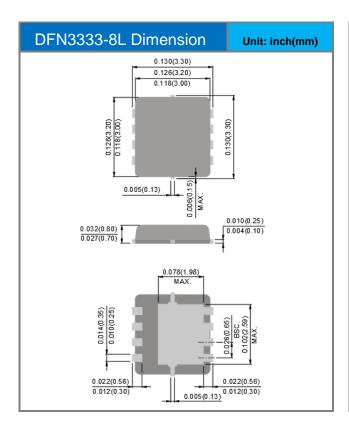


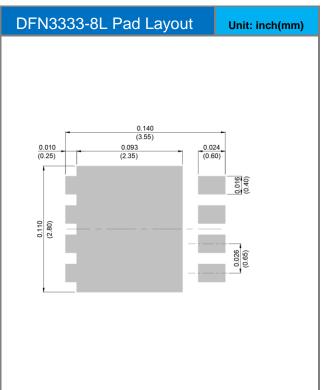


### Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ4442P-AU_R2_000A1	DFN3333-8L	5K pcs / 13" reel	4442	Halogen free RoHS compliant

### **Packaging Information & Mounting Pad Layout**









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